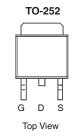
N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	/ _{DS} (V) R _{DS(on)} (Ω)				
60	0.0025 at V _{GS} = 10 V	150			
	0.0051 at V _{GS} = 4.5 V	75			



FEATURES	

- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)							
Parameter	Symbol	Limit	Unit				
Gate-Source Voltage	V _{GS}	± 20	V				
Continuous Drain Current (T _{.1} = 175 °C) ^b	T _C = 25 °C	I_	150				
Continuous Drain Current $(T_J = 175 \text{ C})^2$	T _C = 100 °C	۱ _D	85 ^a				
Pulsed Drain Current	I _{DM}	600	А				
Continuous Source Current (Diode Conduction)	۱ _S	120 ^a					
Avalanche Current	I _{AS}	130					
Single Avalanche Energy (Duty Cycle \leq 1 %)	L = 0.1 mH	E _{AS}	289	mJ			
Maximum Power Dissipation	T _C = 25 °C	P _D	205	W			
	T _A = 25 °C	' D	5.6 ^b	٧V			
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 175	°C				

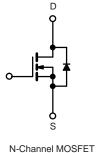
THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Manianum lumation to Archienta	$t \le 10 \text{ sec}$	R _{thJA}	9	15	°C/W		
Maximum Junction-to-Ambient ^a	Steady State		15	45			
Maximum Junction-to-Case		R _{thJC}	0.95	1.5			

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. t \leq 10 s.







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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static	<u> </u>						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$				V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1	-	3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 48 V, V _{GS} = 0 V, T _J = 125 °C			50	μA	
		$V_{DS} = 48 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 175 \text{ °C}$			250		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	150			А	
		V _{GS} = 10 V, I _D = 20 A		0.0025	0.0033		
	P	V_{GS} = 10 V, I _D =20 A, T J = 125 °C		0.0032	0.0040		
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 10 V, I _D =15 A, T _J = 175 °C		0.0039	0.0048	Ω	
		V _{GS} = 4.5 V, I _D = 15 A		0.0051	0.0062		
Forward Transconductance ^b	9 _{fs}	$V_{DS} = 48 \text{ V}, I_{D} = 20 \text{ A}$		166		S	
Dynamic	•						
Input Capacitance	C _{iss}			10120			
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 48 V, f = 1 MHz		1588		pF	
Reverse Transfer Capacitance	C _{rss}			157			
Total Gate Charge ^c	Qg			75	89		
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 48 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		15		nC	
Gate-Drain Charge ^c	Q _{gd}			19			
Turn-On Delay Time ^c	t _{d(on)}			18			
Rise Time ^c	t _r	V_{DD} = 48 V, R_L = 0.6 Ω		32		~~	
Turn-Off Delay Time ^c	t _{d(off)}	$I_{D}\cong$ 20 A, V_{GEN} = 10 V, R_{g} = 2.5 Ω		66		ns	
Fall Time ^c	t _f			13			
Source-Drain Diode Ratings and Ch	aracteristics (T _C = 25 °C)					
Pulsed Current	I _{SM}				600	А	
Diode Forward Voltage	V _{SD}	I _F = 20 A, V _{GS} = 0 V			1.25	V	
Reverse Recovery Time	t _{rr}	I _F = 20 A, di/dt = 100 A/µs		73		ns	

Notes:

a. For design aid only; not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

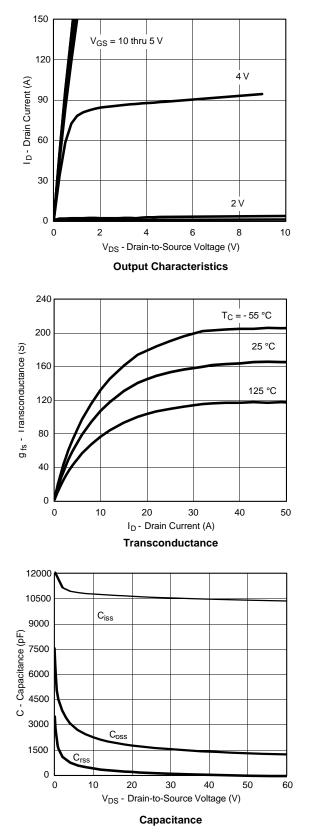
c. Independent of operating temperature.

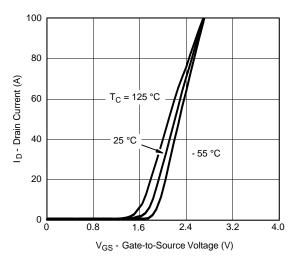
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



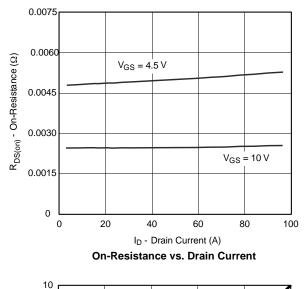
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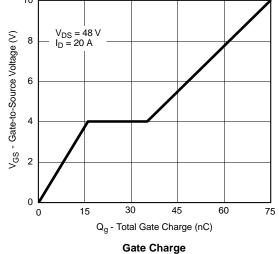
TYPICAL CHARACTERISTICS (25 °C unless noted)





Transfer Characteristics

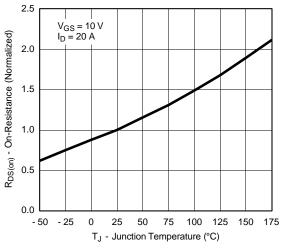




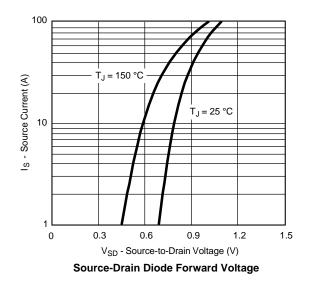


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TYPICAL CHARACTERISTICS (25 °C unless noted)



On-Resistance vs. Junction Temperature

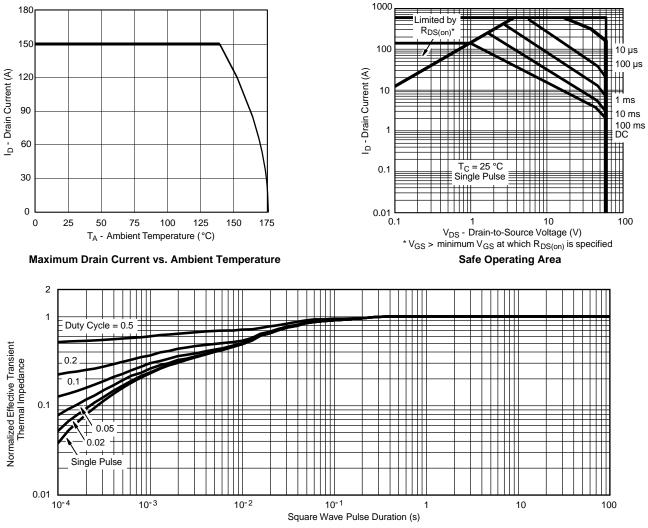




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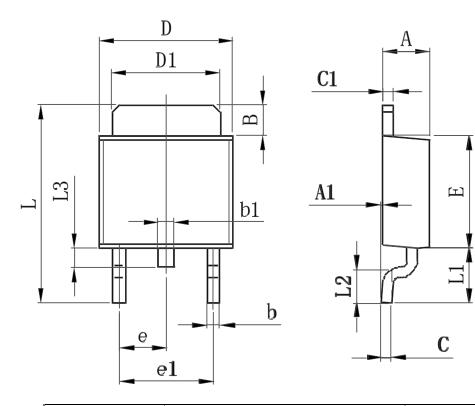


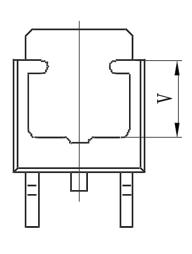


Normalized Thermal Transient Impedance, Junction-to-Case



TO-252-2L PACKAGE OUTLINE DIMENSIONS

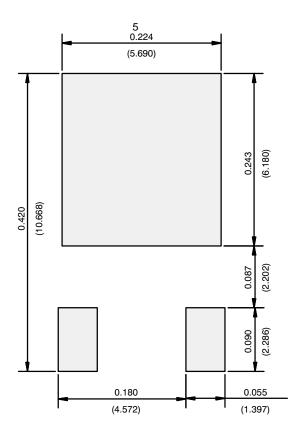




Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
В	1.350	1.650	0.053	0.065	
b	0.500	0.700	0.020	0.028	
b1	0.700	0.900	0.028	0.035	
С	0.430	0.580	0.017	0.023	
c1	0.430	0.580	0.017	0.023	
D	6.350	6.650	0.250	0.262	
D1	5.200	5.400	0.205	0.213	
E	5.400	5.700	0.213	0.224	
е	2.300 TYP.		0.091	TYP.	
e1	4.500	4.700	0.177	0.185	
L	9.500	9.900	0.374	0.390	
L1	2.550	2.900	0.100	0.114	
L2	1.400	1 ¹ .780	0.055	0.070	
L3	0.600	0.900	0.024	0.035	
V	3.800	3.800 REF. 0.150 REF.			



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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